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## Characterisation of capacitively coupled HV/HR-CMOS sensor chips for the CLIC vertex detector

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The capacitive coupling between an active sensor and a readout ASIC has been considered in the framework of the CLIC vertex detector study. The CLICpix Capacitively Coupled Pixel Detector (C3PD) is a High-Voltage CMOS sensor chip produced in a commercial 180 nm HV-CMOS process for this purpose. The sensor was designed to be connected to the CLICpix2 readout chip. It therefore matches the dimensions of the readout chip, featuring a matrix of  $128 \times 128$  square pixels with  $25 \ \mu m$  pitch. The sensor chip has been produced with the standard value for the substrate resistivity (of  $\sim 20 \ \Omega cm$ ) and characterised in standalone testing mode, before receiving and testing capacitively coupled assemblies. The standalone measurement results show a rise time of  $\sim 20$  ns for a power consumption of  $2.7 \ \mu A$ /pixel.

Following the successful characterisation of the C3PD ASICs produced with the standard substrate resistivity a second submission took place, with higher substrate resistivity wafers ( $\sim 20, 80, 200, \text{ and } 1000 \ \Omega \text{cm}$ ). The higher resistivity, along with a layout modification done in order to achieve a higher breakdown voltage, are expected to have beneficial results on the sensor performance. A comparison of the performance of the sensor with different substrate resistivities will be presented.

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**Authors:** KREMASTIOTIS, Iraklis (KIT - Karlsruhe Institute of Technology (DE)); BALLABRIGA SUNE, Rafael (CERN); CAMPBELL, Michael (CERN); DANNHEIM, Dominik (CERN); FIERGOLSKI, Adrian (CERN); HYNDS, Daniel (CERN); KULIS, Szymon (CERN); PERIC, Ivan (KIT - Karlsruhe Institute of Technology (DE))

Presenter: KREMASTIOTIS, Iraklis (KIT - Karlsruhe Institute of Technology (DE))

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